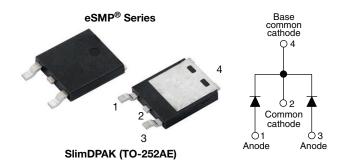
# Vishay Semiconductors

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Hyperfast Rectifier, 2 x 5 A FRED Pt®



# LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 5 A					
V <sub>R</sub>	200 V					
V <sub>F</sub> at I <sub>F</sub>	0.74 V					
t <sub>rr</sub> (typ.)	16 ns					
T <sub>J</sub> max.	175 °C					
Package	SlimDPAK (TO-252AE)					
Circuit configuration	Common cathode					

### FEATURES

- Hyperfast recovery time
- 175 °C max. operating junction temperature
- Low forward voltage drop reduced Q<sub>rr</sub> and soft recovery
- Low leakage current
- Very low profile typical height of 1.3 mm
- Ideal for automated placement
- Polyimide passivation for high reliability standard
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **DESCRIPTION / APPLICATIONS**

State of the art hyper fast recovery rectifiers designed with optimized performance of forward voltage drop, hyper fast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

## MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM R	ATINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V
Average rectified forward current	per leg	I=	T <sub>C</sub> = 165 °C	5	
Average rectilied forward current	per device	IF(AV)	16 = 105 C	10	А
Non-repetitive peak surge current	per leg	I <sub>FSM</sub>	$T_J$ = 25 °C, 10 ms sine pulse wave	100	
Operating junction and storage ten	nperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	200	-	-		
Forward voltage		I <sub>F</sub> = 5 A	0.90	1.04			
	V	I <sub>F</sub> = 10 A	-	1.0	1.17	V	
	V <sub>F</sub>	I <sub>F</sub> = 5 A, T <sub>J</sub> = 150 °C	-	0.74	0.84		
		I <sub>F</sub> = 10 A, T <sub>J</sub> = 150 °C	-	0.85	1.05		
Reverse leakage current per leg	1	$V_{R} = V_{R}$ rated	-	-	4		
	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	80	μA	
Junction capacitance per leg	CT	V <sub>R</sub> = 200 V	-	17	-	pF	

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RoHS COMPLIANT HALOGEN



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST C	TEST CONDITIONS			MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t =$	= 100 A/µs, V <sub>R</sub> = 30 V	-	16	-	
Bayaraa raaayaay tima	+	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1	A, I <sub>RR</sub> = 0.25 A	-	-	25	ns - A
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	21	-	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 5 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 160 V	-	30	-	
Deels receiver a surrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.5	-	
Peak recovery current		T <sub>J</sub> = 125 °C		-	4	-	
Davana waaana ahamaa	0	T <sub>J</sub> = 25 °C		-	25	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	60	-	nc

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C	
Thermal resistance, junction to ambient	R <sub>thJA</sub> <sup>(1)(2)</sup>		-	73	90	°C/W	
Thermal resistance, junction to mount, per diode	R <sub>thJM</sub> <sup>(3)</sup>		-	2.1	2.5	0/10	
Marking device		Case style SlimDPAK (TO-252AE)		10C\	/H02		

#### Notes

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction to ambient;  $dP_D/dT_J < 1R_{thJA}$
- <sup>(2)</sup> Free air, mounted or recommended copper pad area; thermal resistance R<sub>thJA</sub> junction to ambient
- (3) Mounted on infinite heatsink

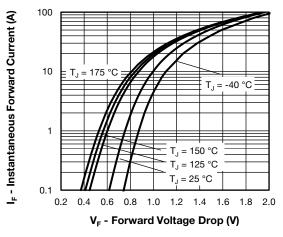


Fig. 1 - Typical Forward Voltage Drop Characteristics

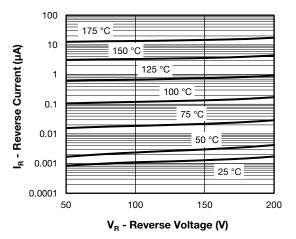


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

# VS-10CVH02HM3

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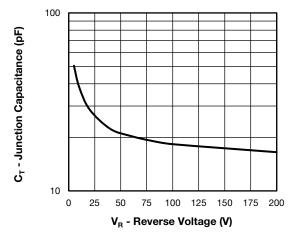


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

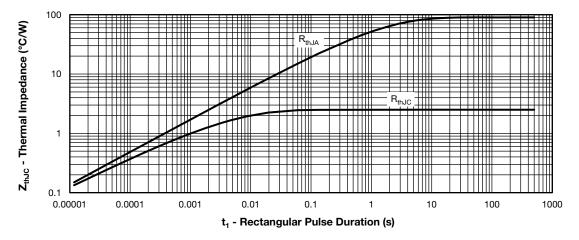
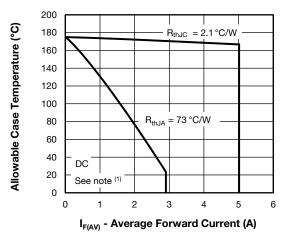
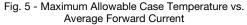


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

Average Power Loss (W)



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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

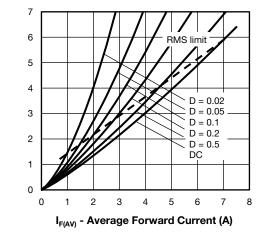


Fig. 6 - Forward Power Loss Characteristics

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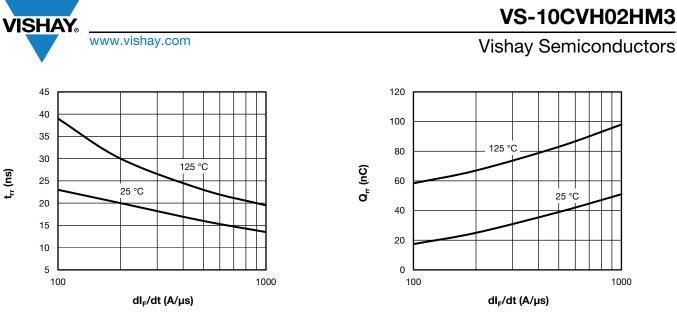


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

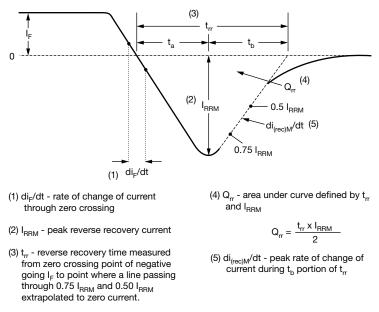


Fig. 9 - Reverse Recovery Waveform and Definitions

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## **ORDERING INFORMATION TABLE**

Device code	VS-	10	с	v	н	02	н	М3
	1	2	3	4	5	6	7	8
	1	- Visl	hay Sen	niconduc	ctors pro	oduct		
	2	- Cur	rent rati	ng (10 =	= 10 A)			
	3	- Circ	cuit conf	iguratior	า:			
		C =	commo	n catho	de			
	4	- V=	SlimDP	AK				
	5		cess typ hyper fa	e, ast recov	very			
	6	- Vol	tage coo	de (02 =	200 V)			
	7	- H=	AEC-Q	101 qua	lified			
	8	- M3	= halog	en-free,	RoHS-0	complia	nt, and	termina

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10CVH02HM3/I	4500	4500	13"diameter plastic tape and reel			

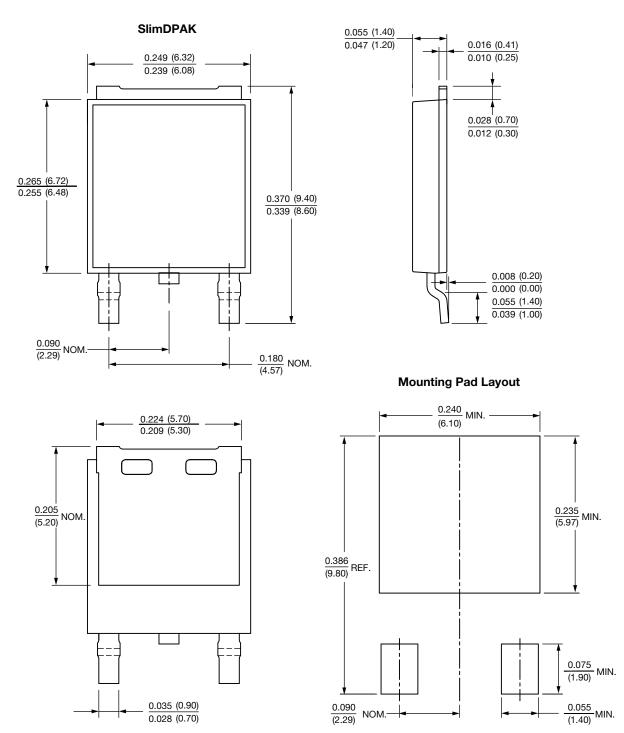
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96081					
Part marking information	www.vishay.com/doc?96085					
Packaging information	www.vishay.com/doc?88869					





SlimDPAK

### **DIMENSIONS** in inches (millimeters)



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 1
 Document Number: 96081

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